NSN 5962-01-039-5040

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-039-5040

3
Overall Length:
Between 1.235 inches and 1.290 inches
Overall Height:
Between 0.275 inches and 0.390 inches
Body Length:
Between 1.235 inches and 1.290 inches
Body Width:

0.500: 1

0.560 inches

Body Height:

Between 0.130 inches and 0.170 inches

Maximum Power Dissipation Rating:

0.165 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

W/strobe and bipolar and programmed and w/enable and 3-state output and hermetically sealed

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

12 input

Current Rating Per Characteristic:

185.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Capitance Rating Per Characteristic:

5.00 input picofarads and 8.00 output picofarads

Time Rating Per Chacteristic:

90.00 nanoseconds access

Memory Device Type:

Prom

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

NSN 5962-01-039-5040

Memory Microcircuit - Page 2 of 2



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Demilitarization:

Yes - demil/mli

Fiig:

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